

### LOW EMI CURRENT SENSE HIGH SIDE SWITCH

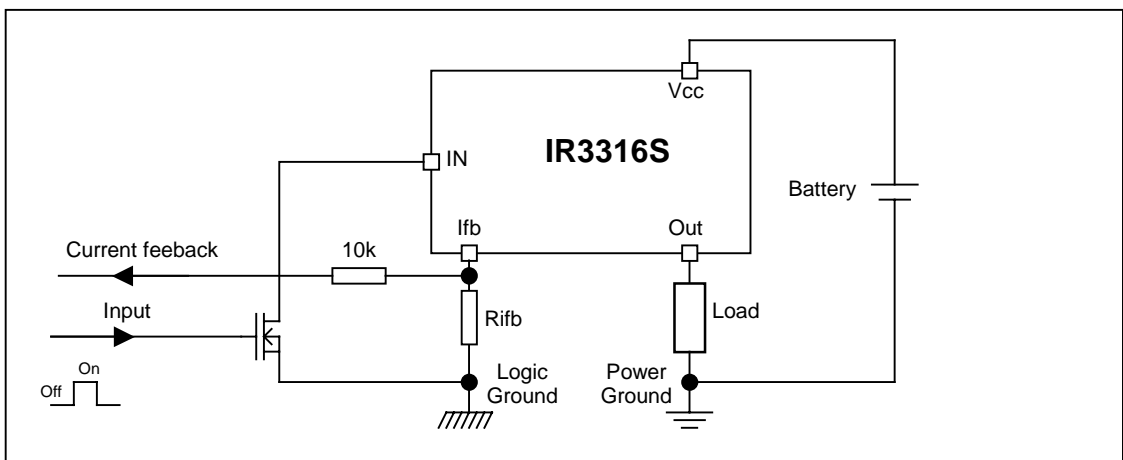
#### Features

- Load current feedback
- Programmable over current shutdown
- Active clamp
- ESD protection
- Input referenced to Vcc
- Over temperature shutdown
- Switching time optimized for low EMI
- Reverse battery protection

#### Description

The IR3316(S)PbF is a fully protected 4 terminals high side switch. The input signal is referenced to Vcc. When the input voltage  $V_{cc} - V_{in}$  is higher than the specified threshold, the output power Mosfet is turned on. When the  $V_{cc} - V_{in}$  is lower than the specified  $V_{il}$  threshold, the output Mosfet is turned off. A current proportional to the power Mosfet current is sourced to the Ifb pin. Over current shutdown occurs when  $V_{st} - V_{in} > 4.5V$ . The current shutdown threshold is adjusted by selecting the proper Rlfb. Either over current and over temperature latches off the switch. The device is reset by pulling the input pin high. Other integrated protections (ESD, reverse battery, active clamp) make the switch very rugged in automotive environment.

#### Typical Connection



#### Product Summary

Rds(on)	7 mΩ max.
Vcc op.	6 to 26V
Current Ratio	8800
Prog. Ishutdown	10 to 90A
Vclamp	40V

#### Packages



TO-220  
IR3316



D<sup>2</sup>Pak  
Pin 4 and 5 fused  
IR3316S

## Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are referenced to Vcc lead. (Tambient=25°C unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vcc-Vin	Maximum Vcc voltage	-16	37	V
Vcc-Vin cont.	Maximum continuous Vcc voltage	-16	26	
Vcc-Vfb	Maximum Ifb voltage	-16	33	
Vcc-Vout	Maximum output voltage	-0.3	37	
I <sub>ds</sub> cont.	Maximum body diode continuous current R <sub>th</sub> =60°C/W (1)	—	2.8	A
I <sub>ds</sub> pulsed	Maximum body diode pulsed current (1)	—	100	
P <sub>d</sub>	Maximum power dissipation R <sub>th</sub> =60°C/W	—	2	W
ESD1	Electrostatic discharge voltage (Human body) C=100pF, R=1500Ω	—	4	kV
ESD2	Electrostatic discharge voltage (Machine Model) C=200pF, R=0Ω	—	0.5	
T <sub>j</sub> max.	Max. storage & operating temperature junction temperature	-40	150	°C
Min R <sub>fb</sub>	Minimum on the resistor on Ifb pin	0.3	—	kΩ
I <sub>fb</sub> max.	Max. Ifb current	-50	50	mA

(1) Limited by junction temperature. Pulsed is also limited by wiring

## Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Units
R <sub>th1</sub>	Thermal resistance junction to ambient D <sup>2</sup> -Pak Std footprint	60	—	°C/W
R <sub>th2</sub>	Thermal resistance junction to case D <sup>2</sup> -Pak	0.7	—	
R <sub>th2</sub>	Thermal resistance junction to case TO220	0.7	—	

## Recommended Operating Conditions

These values are given for a quick design. For operation outside these conditions, please consult the application notes.

Symbol	Parameter	Min.	Max.	Units
I <sub>out</sub>	Continuous output current	—	23	A
	T <sub>ambient</sub> =85°C, R <sub>th</sub> =5°C/W, T <sub>j</sub> =125°C			
	T <sub>ambient</sub> =85°C, R <sub>th</sub> =60°C/W, T <sub>j</sub> =125°C			
R <sub>ifb</sub>	Recommended Ifb resistor (2)(3)	0.5	3.5	kΩ
Pulse min.	Minimum turn-on pulse width	1	—	ms
F <sub>max</sub>	Maximum operating frequency	—	200	Hz

2) If R<sub>ifb</sub> is too low, the device can be damaged.

3) If R<sub>ifb</sub> is too high, the device may not switch on.

## Protection Characteristics

T<sub>j</sub>=25°C, R<sub>ifb</sub>=500 to 5kΩ

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V <sub>ifb-Vin@I<sub>sd</sub></sub>	Over-current shutdown threshold	4	4.7	5.6	V	
T <sub>sd</sub>	Over temperature threshold	—	165	—	°C	See fig. 5
OV	Over voltage protection (not latched)	26	29	33	V	
I <sub>sd</sub> f	Fixed over current shutdown	90	120	140	A	V <sub>ifb</sub> <V <sub>ifb-Vin@I<sub>sd</sub></sub>
I <sub>sd</sub> _1k	Programmable over current shutdown 1k	30	40	50		R <sub>ifb</sub> =1kΩ
T <sub>reset</sub>	Time to reset protection	—	50	500	μs	See fig. 5
Min. pulse	Min. pulse width (no WAIT state)	400	900	2000		
WAIT	WAIT function timer	0.4	1	2	ms	See fig. 4 and 5
R <sub>ds(on)</sub> rev.	Reverse battery On state resistance	4	6.7	10	mΩ	V <sub>cc-Vin</sub> =-14V, I <sub>out</sub> =30A

## Static Electrical Characteristics

T<sub>j</sub>=25°C, V<sub>cc</sub>=14V (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
V <sub>cc op.</sub>	Operating Voltage range	6	—	26	V	
I <sub>cc off</sub>	Supply leakage current	—	1.5	5	μA	V <sub>in</sub> =V <sub>cc</sub> , V <sub>cc-Vout</sub> =14V, V <sub>cc-Vifb</sub> =14V
I <sub>in, on</sub>	On state I <sub>N</sub> positive current	1.5	3	6	mA	V <sub>cc-Vin</sub> =14V
V <sub>ih</sub>	High level Input threshold voltage (4)	—	5.4	6.2	V	
V <sub>il</sub>	Low level Input threshold voltage (4)	4	4.9	5.8		
V <sub>hyst</sub>	Input hysteresis V <sub>ih</sub> -V <sub>il</sub>	0.2	0.4	1		
I <sub>out</sub>	Drain to source leakage current	—	1.2	5	μA	V <sub>in</sub> =V <sub>cc</sub> , V <sub>cc-Vifb</sub> =0V, V <sub>cc-Vout</sub> =14V
R <sub>ds(on)</sub>	On state resistance (5) T <sub>j</sub> =25°C	4	5.5	7	mΩ	I <sub>out</sub> =30A, V <sub>cc-Vin</sub> =14V
	On state resistance (5) T <sub>j</sub> =25°C	4	6	10		I <sub>out</sub> =17A, V <sub>cc-Vin</sub> =6V
	On state resistance (5)(6) T <sub>j</sub> =150°C	7	10.5	13.5		I <sub>out</sub> =30A, V <sub>cc-Vin</sub> =14V
V <sub>clamp1</sub>	V <sub>cc</sub> to V <sub>out</sub> clamp voltage 1	36	39	—	V	I <sub>out</sub> =50mA
V <sub>clamp2</sub>	V <sub>cc</sub> to V <sub>out</sub> clamp voltage 2	—	40	43		I <sub>out</sub> =30A

(4) Input thresholds are measured directly between the input pin and the tab. Any parasitic resistance in common between the load current path and the input signal path can significantly affect the thresholds.

(5) R<sub>ds(on)</sub> is measured between the tab and the Out pin, 5mm away from the package.

(6) Guaranteed by design

## Switching Electrical Characteristics

V<sub>cc</sub>=14V, Resistive load=0.5Ω, T<sub>j</sub>=25°C

Symbol	Parameter	Min.	Typ.	Max.	Units	Test Conditions
T <sub>don</sub>	Turn on delay time to 10% V <sub>cc</sub>	30	120	300	μs	See figure 2
T <sub>r1</sub>	Rise time to V <sub>cc-Vout</sub> =5V	20	50	125		
T <sub>r2</sub>	Rise time to V <sub>cc-Vout</sub> =0.1V <sub>cc</sub>	30	80	200		
E <sub>on</sub>	Turn on energy	—	14	—	mJ	
T <sub>doff</sub>	Turn off delay time	30	140	350	μs	
T <sub>f</sub>	Fall time to V <sub>out</sub> =10% of V <sub>cc</sub>	35	100	250		
E <sub>off</sub>	Turn off energy	—	7	—	mJ	





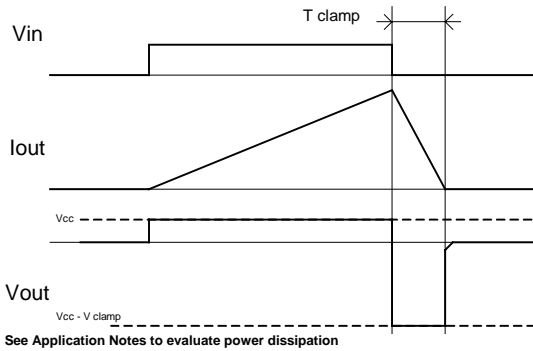


Figure 3 – Active clamp waveforms

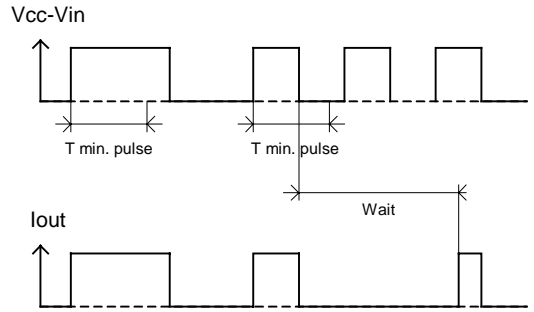


Figure 4 – Min. pulse and Wait function

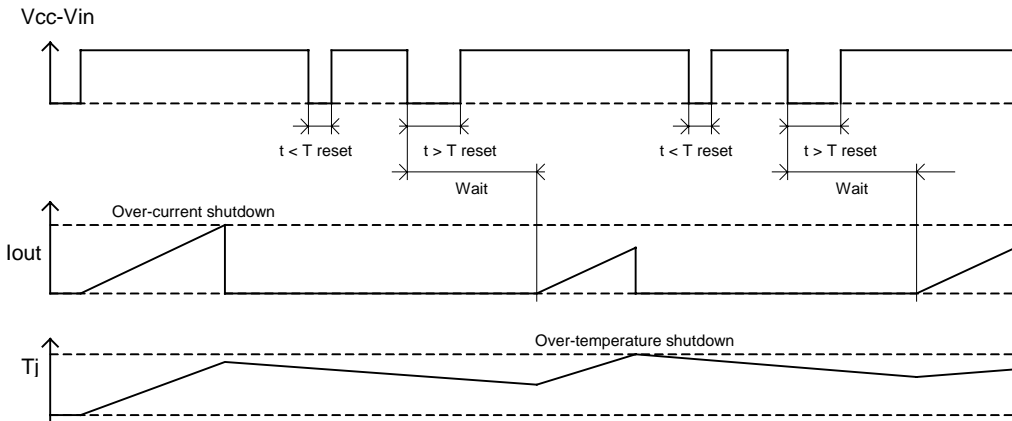


Figure 5 – Protection Timing Diagrams

All curves are typical characteristics. Operation in hatched areas is not recommended.  $T_j=25^\circ\text{C}$ ,  $R_{\text{th}}=500\text{ohm}$ ,  $V_{\text{cc}}=14\text{V}$  (unless otherwise specified).

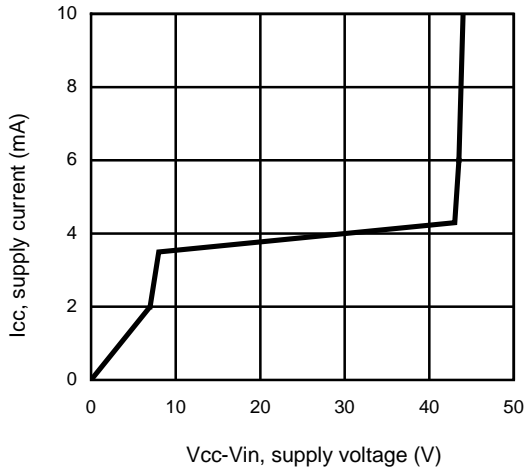


Figure 6 – Icc (mA) Vs Vcc-Vin (V)

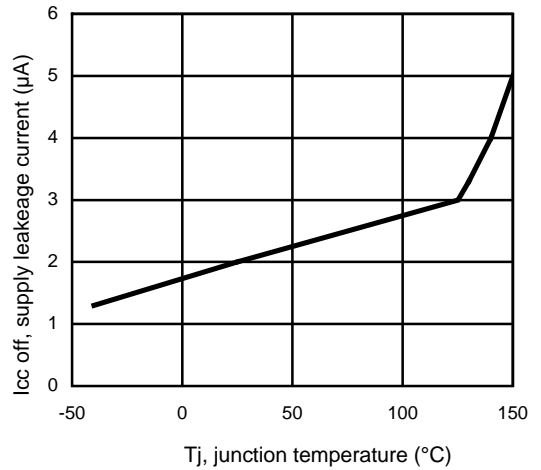


Figure 7 – Icc off (μA) Vs Tj (°C)

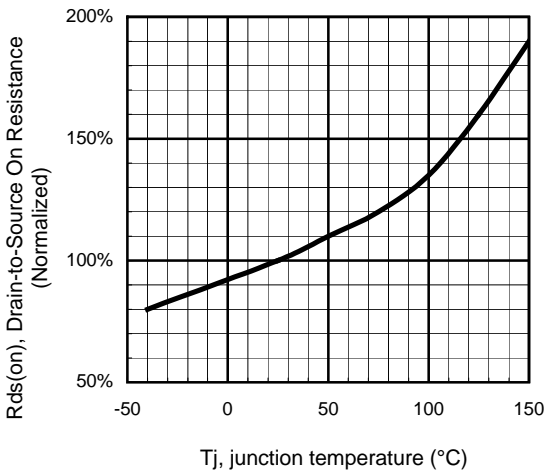


Figure 8 - Normalized Rds(on) (%) Vs Tj (°C)

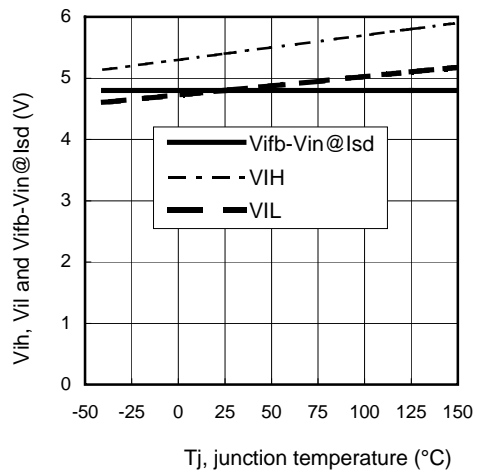


Figure 9 – Vih, Vil and Vf(b)-Vin@I(s,d) (V) Vs Tj (°C)

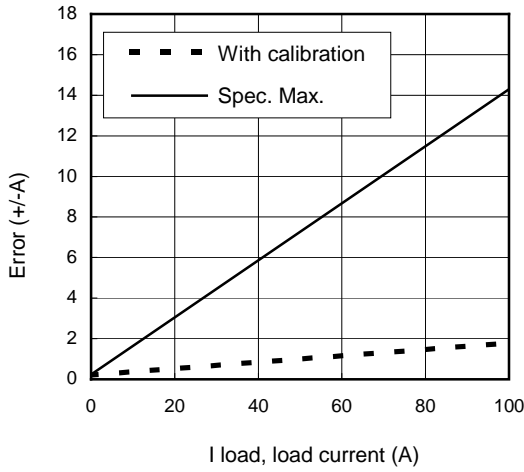


Figure 10 – Error (+/- A) Vs I load (A)

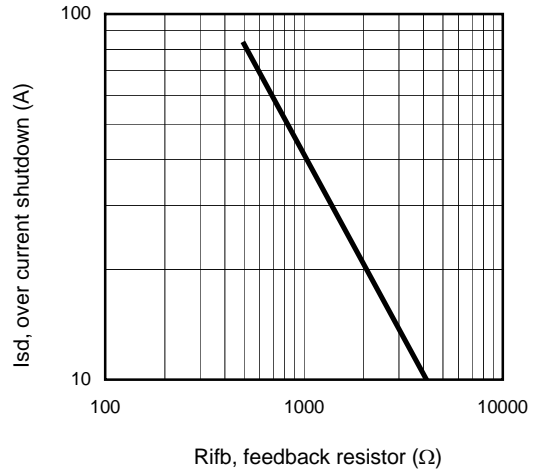


Figure 11 – Ids (A) Vs Rifb (Ω)

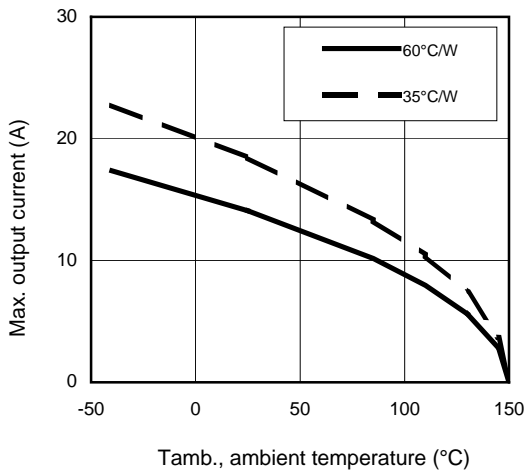


Figure 12 – Max. iout (A) Vs Tamb. (°C)

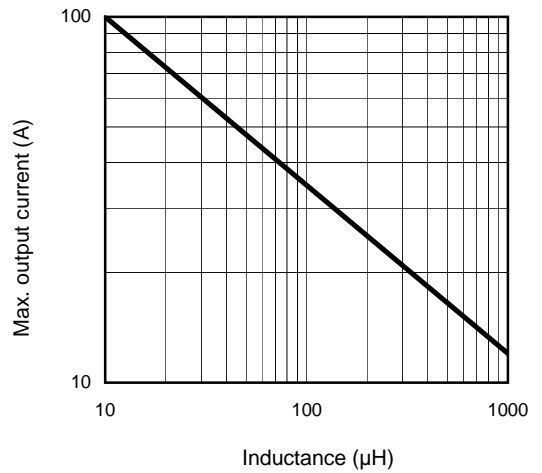
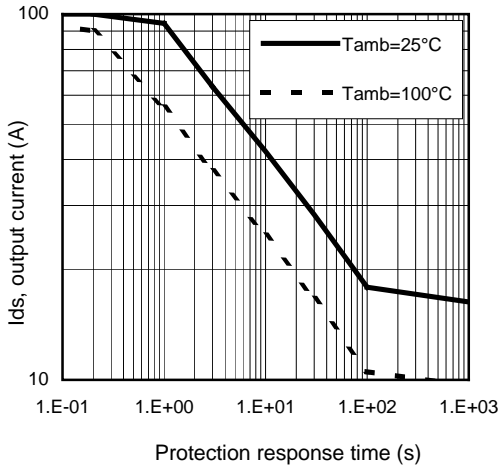
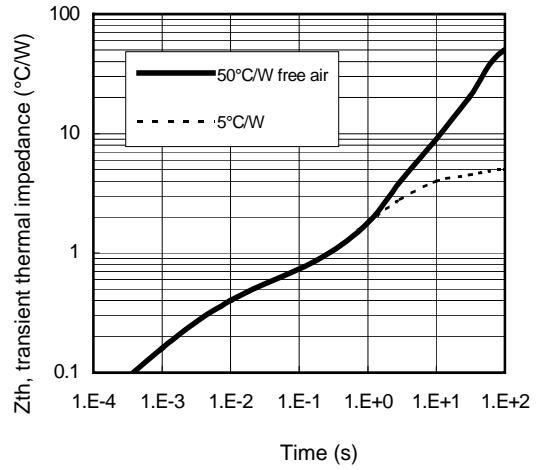


Figure 13 – Max. iout (A) Vs inductance (μH)



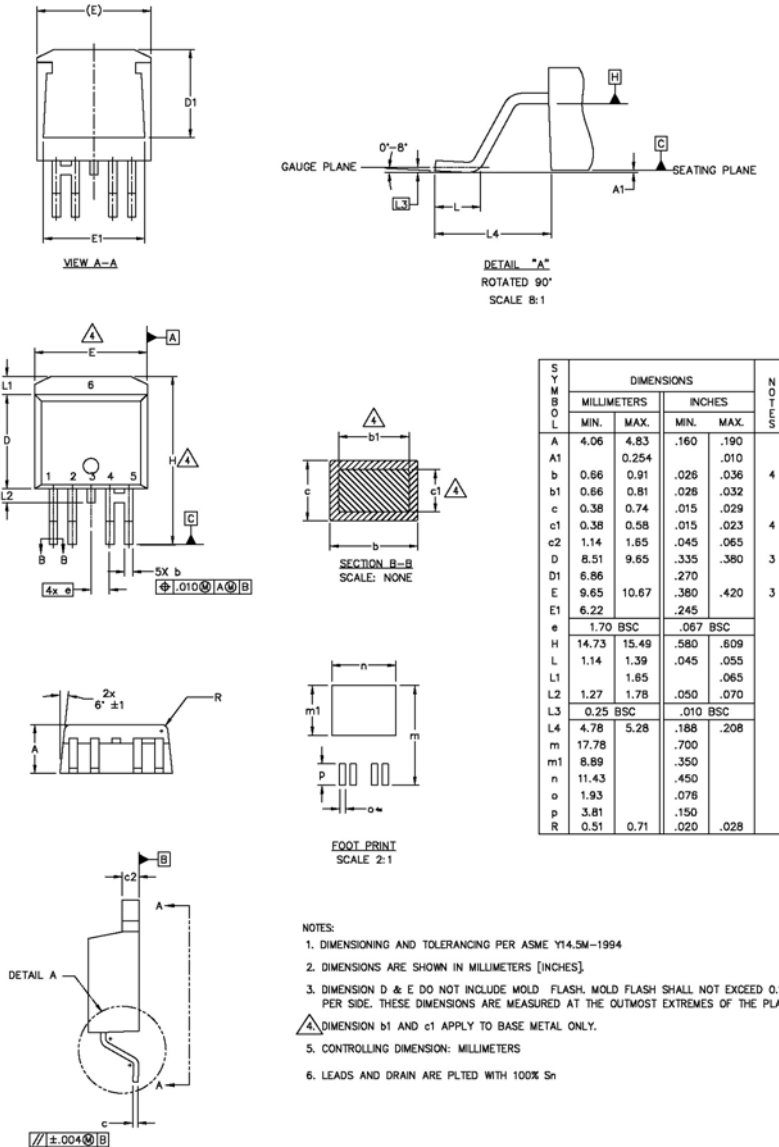


**Figure 14 – Ids (A) Vs over temperature protection response time (s)**

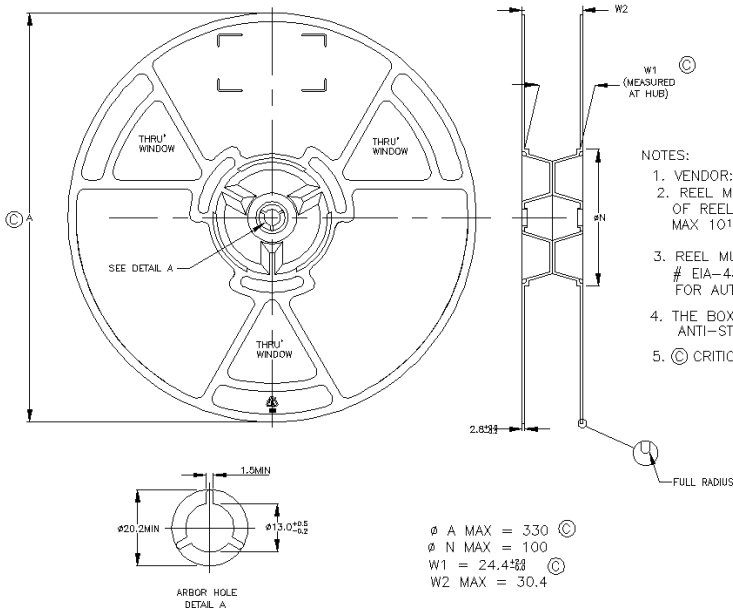


**Figure 15 – Transient thermal impedance (°C/W) Vs time (s)**

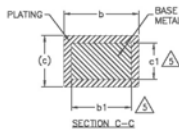
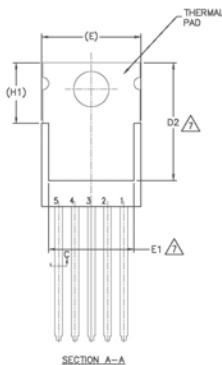
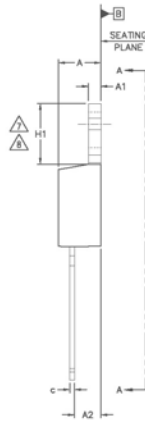
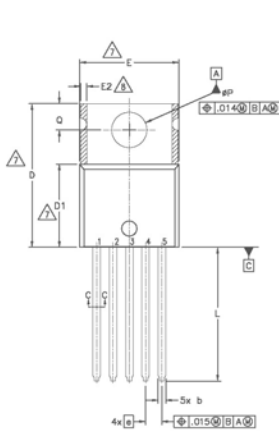
## Case Outline 5 Lead - D2PAK - Automotive Q100 PbF MSL1 qualified



## Tape & Reel 5 Lead - D2PAK



Case Outline 5 Leads – TO220 – Automotive Q100 PbF qualified



DIMENSION	DIMENSIONS				NOMINAL VALUE
	MILLIMETERS		INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	3.56	4.83	.140	.190	
A1	0.51	1.40	.020	.055	
A2	2.03	2.92	.080	.115	
b	0.64	0.89	.025	.035	
bt	0.64	0.84	.025	.033	5
c	0.36	0.61	.014	.024	
c1	0.36	0.56	.014	.022	5
D	14.22	16.51	.560	.650	4
D1	6.38	9.02	.330	.355	
D2	11.68	12.88	.460	.507	7
E	9.65	10.67	.380	.420	4,7
E1	6.86	8.89	.270	.350	7
E2	-	0.76	-	.030	8
e	1.70 BSC		.067 BSC		
H1	5.84	6.96	.230	.270	7,8
L	12.70	14.73	.500	.580	
ϕP	3.53	3.73	.139	.147	
Q	2.54	3.05	.100	.120	

- NOTES:
- 1.- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5 M-1994.
  - 2.- DIMENSIONS ARE SHOWN IN INCHES [MILLIMETERS].
  - 3.- LEAD DIMENSION AND FINISH UNCONTROLLED IN L1.
  - 4.- DIMENSION D1, D1 & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005" (0.127) PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
  - 5.- DIMENSION bt & c1 APPLY TO BASE METAL ONLY.
  - 6.- CONTROLLING DIMENSION - INCHES.
  - 7.- THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS E,H1,D2 & E1.
  - 8.- DIMENSION E2 X H1 DEFINE A ZONE WHERE STAMPING AND SINGULATION IRREGULARITIES ARE ALLOWED.
  - 9.- OUTLINE CONFORMS TO JEDEC TO-220, EXCEPT A2 (max.) AND D3 (min.) WHERE DIMENSIONS ARE DERIVED FROM THE ACTUAL PACKAGE OUTLINE.
  - 10.- LEADS AND DRAIN ARE PLATED WITH 100% Sn